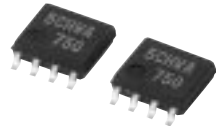


FY5ACH-03A

HIGH-SPEED SWITCHING USE

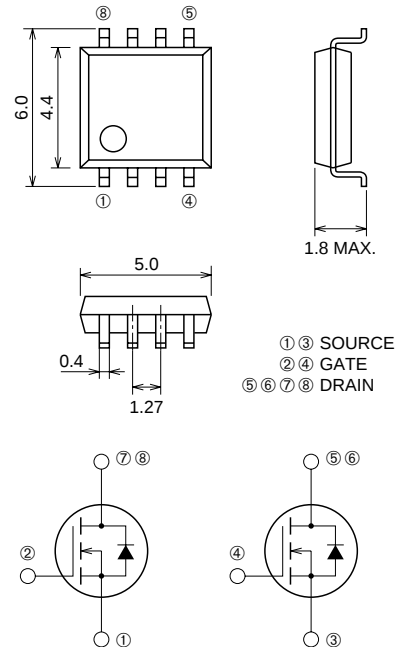
FY5ACH-03A



- 2.5V DRIVE
- V_{DS} 30V
- $r_{DS(ON)}$ (MAX) 50m Ω
- I_D 5A

OUTLINE DRAWING

Dimensions in mm



SOP-8

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (T_c = 25°C)

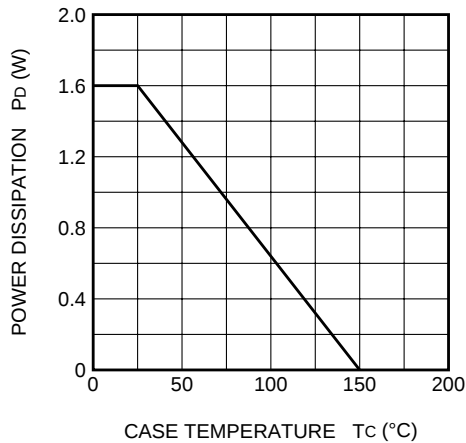
Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	30	V
V_{GS}	Gate-source voltage	$V_{DS} = 0V$	± 10	V
I_D	Drain current		5	A
I_{DM}	Drain current (Pulsed)		35	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 10\mu H$	5	A
I_S	Source current		1.7	A
I_{SM}	Source current (Pulsed)		6.8	A
P_D	Maximum power dissipation		1.6	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	0.07	g

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

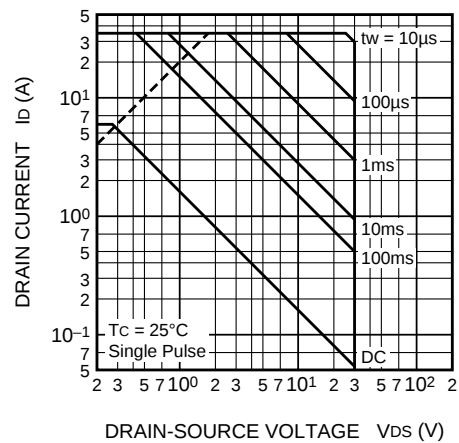
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{(BR) DSS}	Drain-source breakdown voltage	I _D = 1mA, V _{DS} = 0V	30	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±10V, V _{DS} = 0V	—	—	±0.1	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 30V, V _{GS} = 0V	—	—	0.1	mA
V _{GS(th)}	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	0.5	0.9	1.3	V
r _{DS(ON)}	Drain-source on-state resistance	I _D = 5A, V _{GS} = 4V	—	40	50	mΩ
r _{DS(ON)}	Drain-source on-state resistance	I _D = 2.5A, V _{GS} = 2.5V	—	52	80	mΩ
V _{DS(ON)}	Drain-source on-state voltage	I _D = 5A, V _{GS} = 4V	—	0.20	0.25	V
y _{fs}	Forward transfer admittance	I _D = 5A, V _{DS} = 10V	—	11	—	S
C _{iss}	Input capacitance	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	—	750	—	pF
C _{oss}	Output capacitance		—	180	—	pF
C _{rss}	Reverse transfer capacitance		—	80	—	pF
t _{d(on)}	Turn-on delay time	V _{DD} = 15V, I _D = 2.5A, V _{GS} = 4V, R _{GEN} = R _{GS} = 50Ω	—	18	—	ns
t _r	Rise time		—	45	—	ns
t _{d(off)}	Turn-off delay time		—	52	—	ns
t _f	Fall time		—	44	—	ns
V _{SD}	Source-drain voltage	I _S = 1.7A, V _{GS} = 0V	—	0.75	1.1	V
R _{th(ch-a)}	Thermal resistance	Channel to ambient	—	—	78.1	°C/W
t _{rr}	Reverse recovery time	I _S = 1.7A, di _s /dt = -50A/μs	—	100	—	ns

PERFORMANCE CURVES

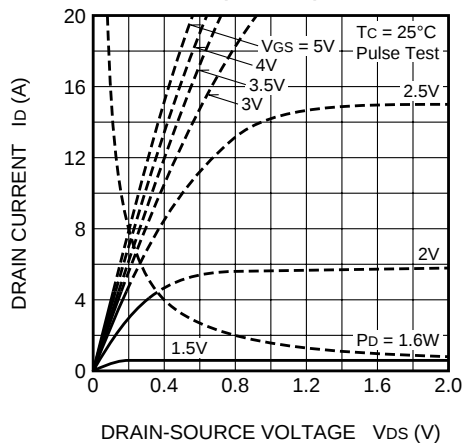
POWER DISSIPATION DERATING CURVE



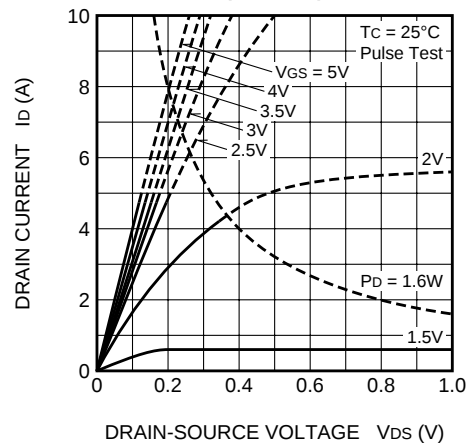
MAXIMUM SAFE OPERATING AREA



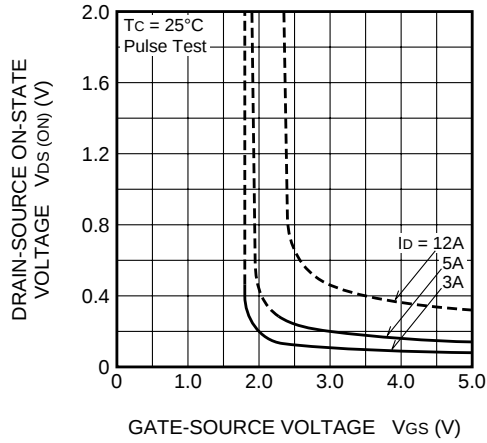
OUTPUT CHARACTERISTICS (TYPICAL)



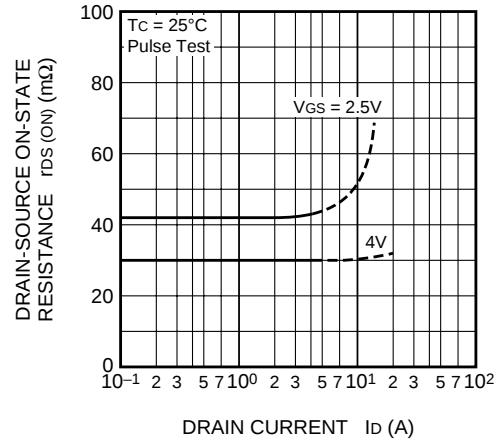
OUTPUT CHARACTERISTICS (TYPICAL)



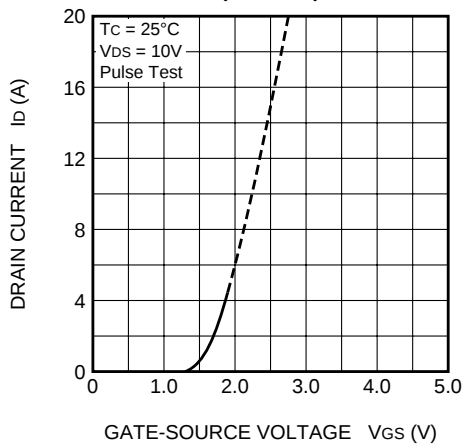
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



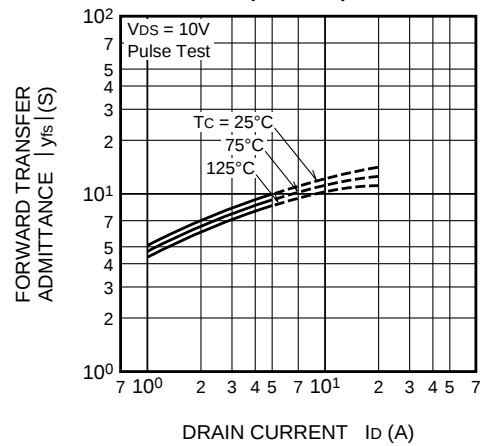
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



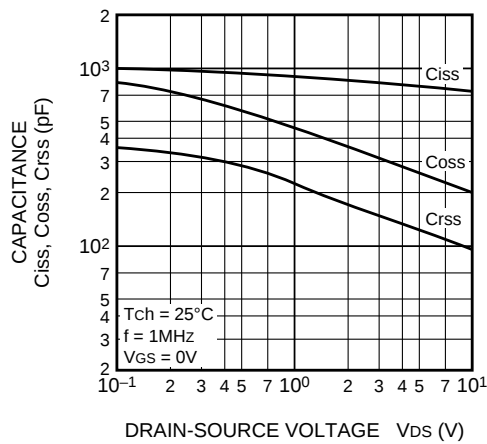
TRANSFER CHARACTERISTICS
(TYPICAL)



FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)



CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



SWITCHING CHARACTERISTICS
(TYPICAL)

